Low-Voltage Single-Supply, SPDT Analog Switch in SC-70

DESCRIPTION

The DG4599 is a cost effective upgrade to other types of 4599 low-voltage, single-pole/double-throw analog switches available in the industry today.

Combining low power, high speed, low on-resistant and small physical size, the DG4599 is ideal for portable and battery powered applications.

The DG4599 is built on Vishay Siliconix's low voltage CMOS process. An epitaxial layer prevents latchup. Break-before - make is guaranteed for DG4599.

Each switch conducts equally well in both directions when on, and blocks up to the power supply level when off.

FEATURES

- 6-Pin SC-70 Package
- 60 Ω Max. (26 Typ.) On-Resistance
- 2 Ω Typ. R_{ON} Flatness
- Fast Switching: t_{ON} = 30 ns (Max.)
  t_{OFF} = 25 ns (Max.)
- 2.25 V to 5.5 V Single Supply Operation
- Break-Before-Make Switching
- TTL/CMOS-Logic Compatible

Pb-free Available

RoHS* COMPLIANT

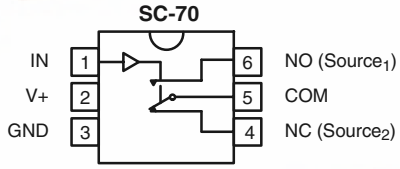
BENEFITS

- Reduced Power Consumption
- Simple Logic Interface
- High Accuracy
- Reduce Board Space

APPLICATIONS

- Battery-Operated Equipment
- Audio and Video Signal Routing
- Cellular Phones
- Low-Voltage Data-Acquistion Systems
- Sample-and-Hold Circuits
- Communications Systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Top View

Device Marking: 4J

TRUTH TABLE		
Logic	**NC**	**NO**
0	ON	OFF
1	OFF	ON

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

ORDERING INFORMATION		
Temp Range	**Package**	**Part Number**
- 40 to 85 °C	SC70-6	DG4599DL-T1 DG4599DL-T1-E3

* Pb containing terminations are not RoHS compliant, exemptions may apply

ABSOLUTE MAXIMUM RATINGS

Parameter		Limit	Unit
Referenced V+ to GND		- 0.3 to + 6	V
IN, COM, NC, NO[a]		- 0.3 to (V+ + 0.3)	
Continuous Current (Any Terminal)		± 50	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle)		± 200	
Storage Temperature (D Suffix)		- 65 to 125	°C
Power Dissipation (Packages)[b]	6-Pin SO70[c]	250	mW

Notes:
a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC Board.
c. Derate 6.5 mW/°C above 25 °C.

SPECIFICATIONS (V+ = 5 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 5 V, ± 10 %, V_{IN} = 0.8 or 2.4 V[e]	Temp[a]	Limits - 40 to 85 °C Min[b]	Typ[c]	Max[b]	Unit
Analog Switch							
Analog Signal Range[d]	V_{NO}, V_{NC} V_{COM}		Full	0		V+	V
Drain-Source On-Resistance	$r_{DS(on)}$	V+ = 4.5 V, V_D = 3 V, I_S = 10 mA	Room Full		7 10	60 65	Ω
$r_{DS(on)}$ Flatness[d]	$r_{DS(on)}$ Flatness	V+ = 2.5 V	Room		2		
Switch Off Leakage Current	$I_{S(off)}$	V+ = 5.5 V V_S = 1 V/4.5 V, V_D = 4.5 V/1 V	Room Full	- 1.0 - 4.0		1.0 4.0	nA
	$I_{D(off)}$		Room Full	- 1.0 - 4.0		1.0 4.0	
Channel-On Leakage Current	$I_{D(on)}$	V+ = 5.5 V, V_S = V_D = 1 V/4.5 V	Room Full	- 1.0 - 3.0		1.0 4.5	
Digital Control							
Input High Voltage	V_{INH}		Full	2.4			V
Input Low Voltage	V_{INL}		Full			0.8	
Input Capacitance	C_{in}		Full		3		pF
Input Current	I_{INL} or I_{INH}	V_{IN} = 0 or V+	Full	- 1		1	µA
Dynamic Characteristics							
Turn-On Time[d]	t_{ON}	V_D or V_S = 3 V, R_L = 300 Ω, C_L = 35 pF Figures 1 and 2	Room Full		9	30 40	ns
Turn-Off Time[d]	t_{OFF}		Room Full		5	25 30	
Break-Before-Make Time[d]	t_d		Room	1	4		
Charge Injection[d]	Q_{INJ}	C_L = 1 nF, V_S = 0 V V_{GEN} = 0 V, R_{GEN} = 0 Ω, Figure 3	Room		5	10	pC
Off-Isolation[d]	OIRR	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room		- 73		dB
Crosstalk[d]	X_{TALK}		Room		- 70		
Source-Off Capacitance[d]	$C_{S(off)}$	V_{IN} = 0 or V+, f = 1 MHz	Room		7		pF
Channel-On Capacitance[d]	$C_{D(on)}$		Room		20		
Drain-to-Source Capacitance[d]	$C_{DS(off)}$		Room		20		
Power Supply							
Power Supply Range	V+			4.5		5.5	V
Power Supply Current	I+	V_{IN} = 0 or V+			0.01	1.0	µA
Power Consumption	P_C					5.5	µW

SPECIFICATIONS (V+ = 3 V)							
		Test Conditions Otherwise Unless Specified		Limits - 40 to 85 °C			
Parameter	Symbol	V+ = 3 V, ± 10 %, V_{IN} = 0.4 or 2.0 V[e]	Temp[a]	Min[b]	Typ[c]	Max[b]	Unit
Analog Switch							
Analog Signal Range[d]	V_{NO}, V_{NC} V_{COM}		Full	0		V+	V
Drain-Source On-Resistance[d]	$r_{DS(on)}$	V+ = 2.7 V, V_D = 1.5 V, I_S = 10 mA	Room Full		15 19	95 105	Ω
$r_{DS(on)}$ Flatness[d]	$r_{DS(on)}$ Flatness	V_S = 0 to V+, I_S = 10 mA	Room		7.5		
Digital Control							
Input High Voltage	V_{INH}		Full	2			V
Input Low Voltage	V_{INL}		Full			0.8	
Input Current	I_{INL} or I_{INH}	V_{IN} = 0 or V+	Full	- 1		1	µA
Dynamic Characteristics							
Turn-On Time[d]	t_{ON}	V_D or V_S = 2.0 V, R_L = 300 Ω, C_L = 35 pF Figures 1 and 2	Room Full		12	45 55	ns
Turn-Off Time[d]	t_{OFF}		Room Full		6	35 40	
Break-Before-Make Time[d]	t_d		Room	1	7		
Charge Injection[d]	Q_{INJ}	C_L = 1 nF, V_{GEN} = 0 V, V_S = 0 V R_{GEN} = 0 Ω, Figure 3	Room		5	10	pC
Power Supply							
Power Supply Range	V+			2.7		3.3	V
Power Supply Current	I+	V_{IN} = 0 or V+			0.01	1.0	µA
Power Consumption	P_C					3.3	µW

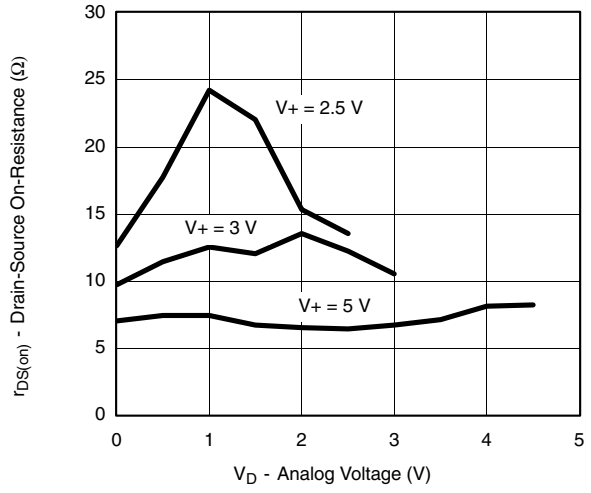
SPECIFICATIONS (V+ = 2.5 V)

Parameter	Symbol	Test Conditions Otherwise Unless Specified V+ = 2.5 V, ± 10 %, V_{IN} = 0.4 or 2.0 V[e]	Temp[a]	Limits - 40 to 85 °C Min[b]	Typ[c]	Max[b]	Unit
Analog Switch							
Analog Signal Range[d]	V_{NO}, V_{NC} V_{COM}		Full	0		V+	V
Drain-Source On-Resistance	$r_{DS(on)}$	V+ = 2.25 V, V_D = 1.0 V, I_S = 10 mA	Room Full[d]		26 29	110 120	Ω
$r_{DS(on)}$ Flatness[d]	$r_{DS(on)}$ Flatness	V+ = 2.5 V	Room		10		Ω
Digital Control							
Input High Voltage	V_{INH}		Full	2			V
Input Low Voltage	V_{INL}		Full			0.4	V
Input Current	I_{INL} or I_{INH}	V_{IN} = 0 or V+	Full	- 1		1	µA
Dynamic Characteristics							
Turn-On Time	t_{ON}	V_D or V_S = 1.5 V, R_L = 300 Ω, C_L = 35 pF Figures 1 and 2	Room Full[d]		16	50 60	ns
Turn-Off Time	t_{OFF}		Room Full[d]		7	35 45	ns
Break-Before-Make Time	t_d		Room	1	12		ns
Power Supply							
Power Supply Range	V+			2.25		2.75	V
Power Supply Current[d]	I+	V_{IN} = 0 or V+			0.01	1.0	µA
Power Consumption	P_C					2.75	µW

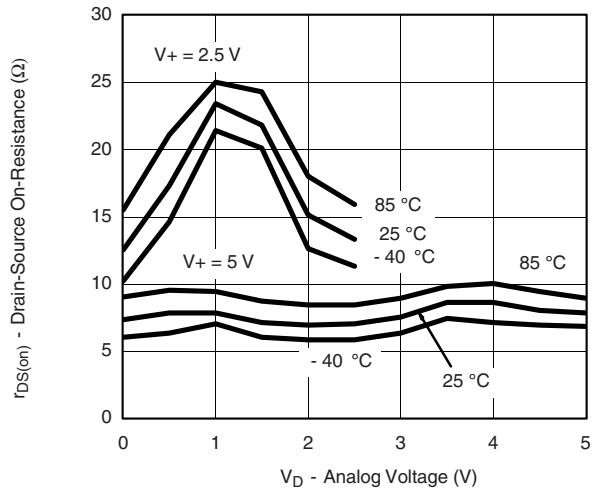
Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

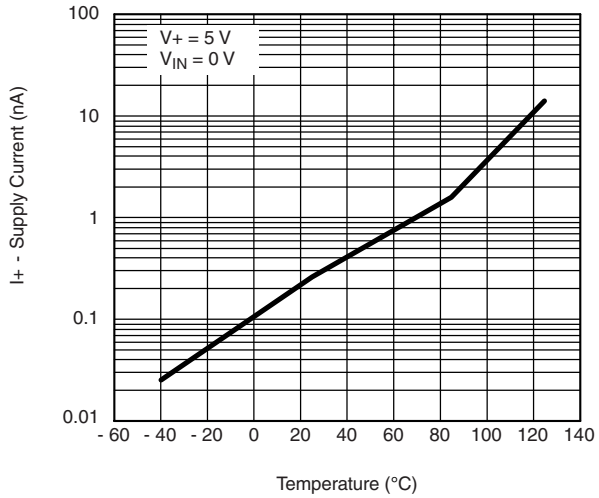
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



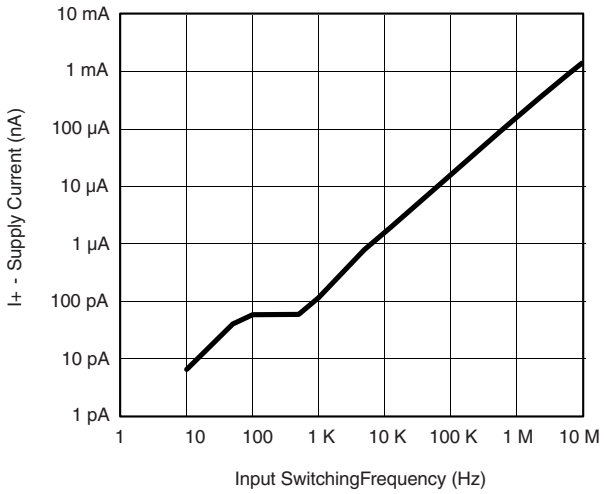
$r_{DS(on)}$ vs. Analog and Power Voltage



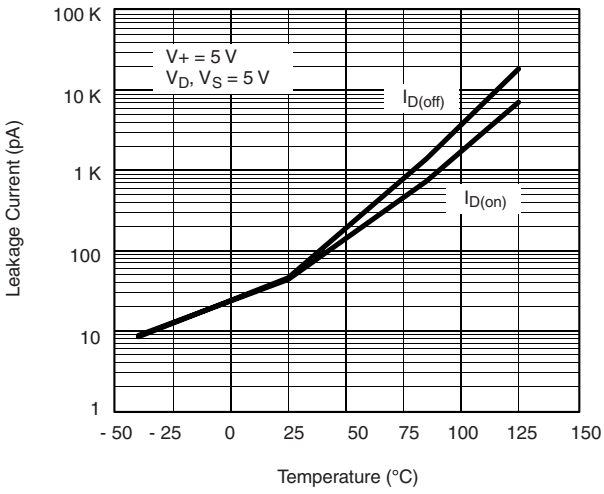
$r_{DS(on)}$ vs. Analog Voltage and Temperature



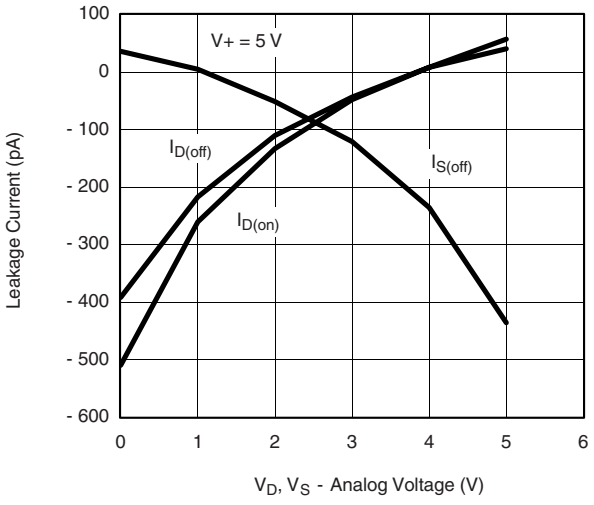
Supply Current vs. Temperature



Supply Current vs. Input Switching Frequency

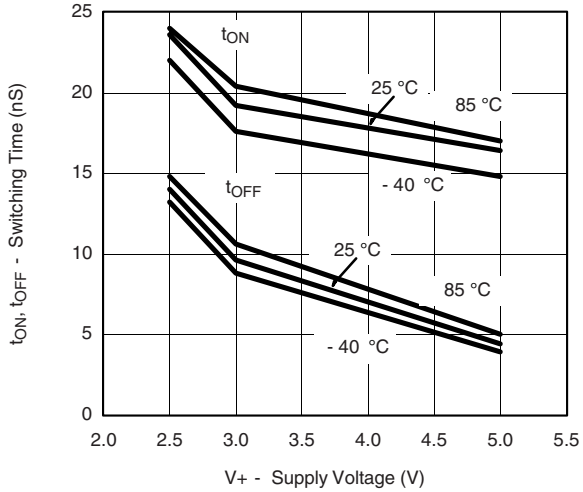


Leakage Current vs. Temperature

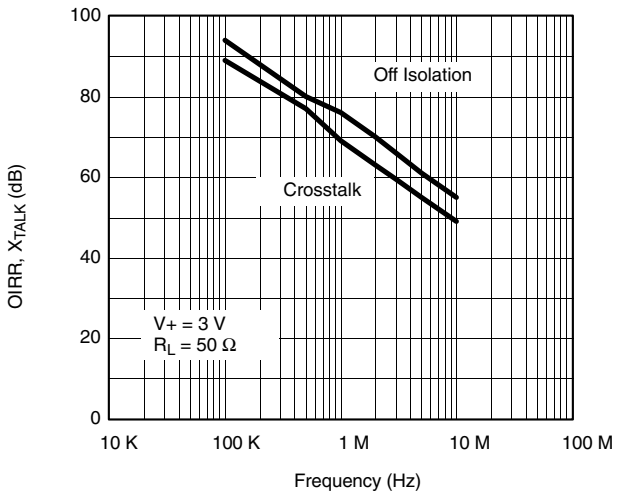


Leakage vs. Analog Voltage

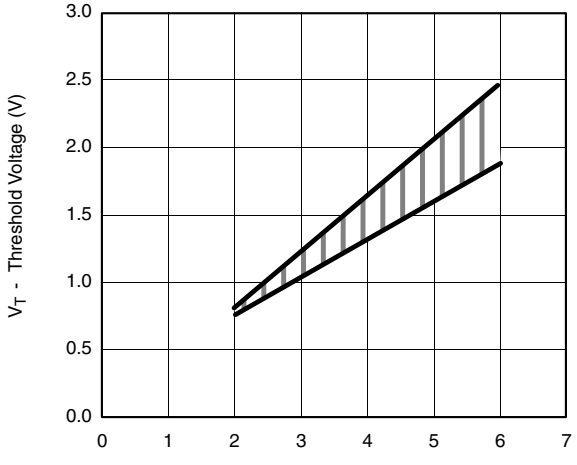
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



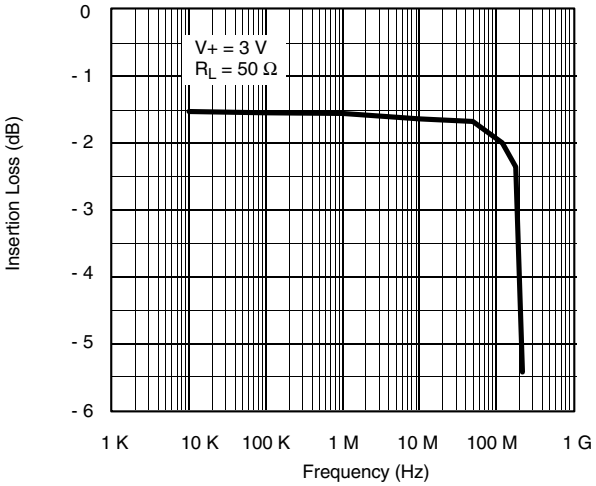
Switching Time vs. Temperature and Supply Voltage



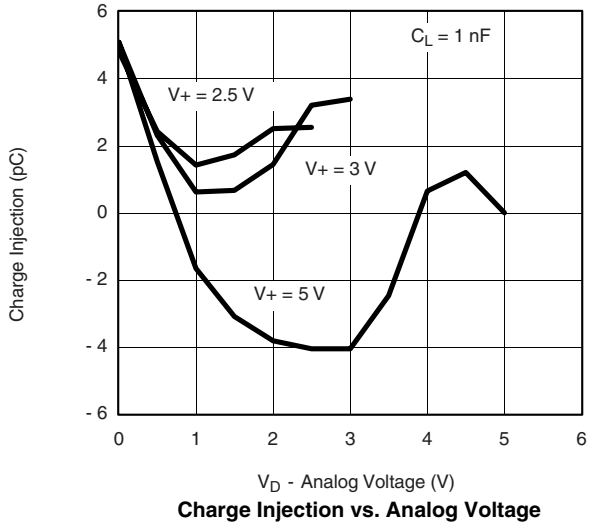
Crosstalk and Off Isolation vs. Frequency



Input Switching Threshold vs. Supply Voltage



Insertion Loss vs. Frequency



Charge Injection vs. Analog Voltage

TEST CIRCUITS

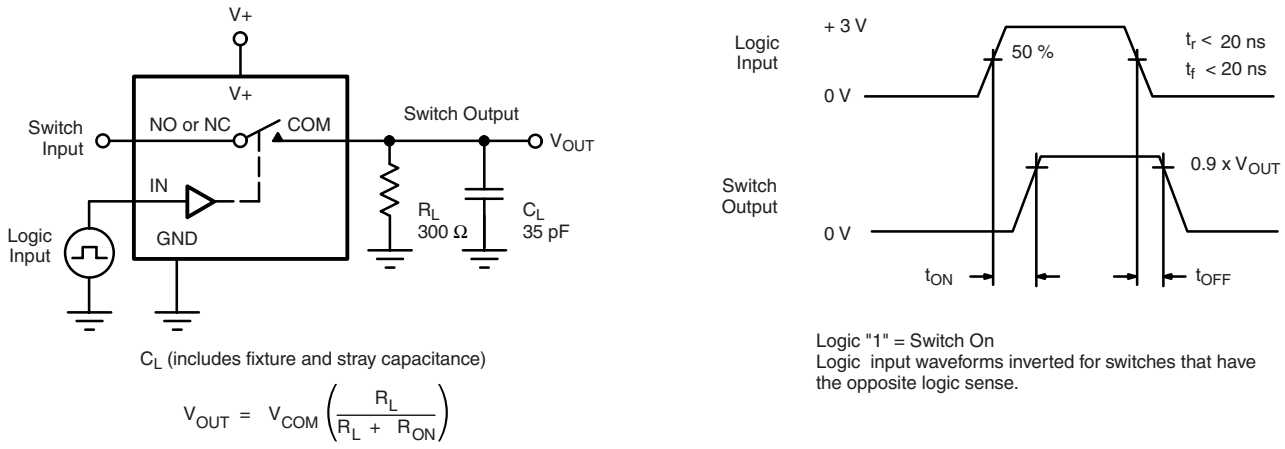


Figure 1. Switching Time

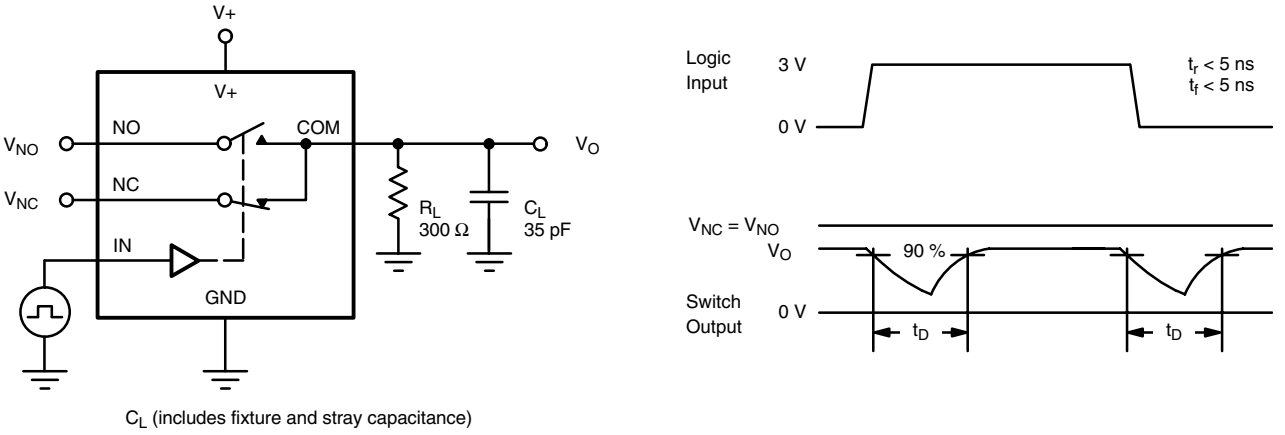


Figure 2. Break-Before-Make Interval

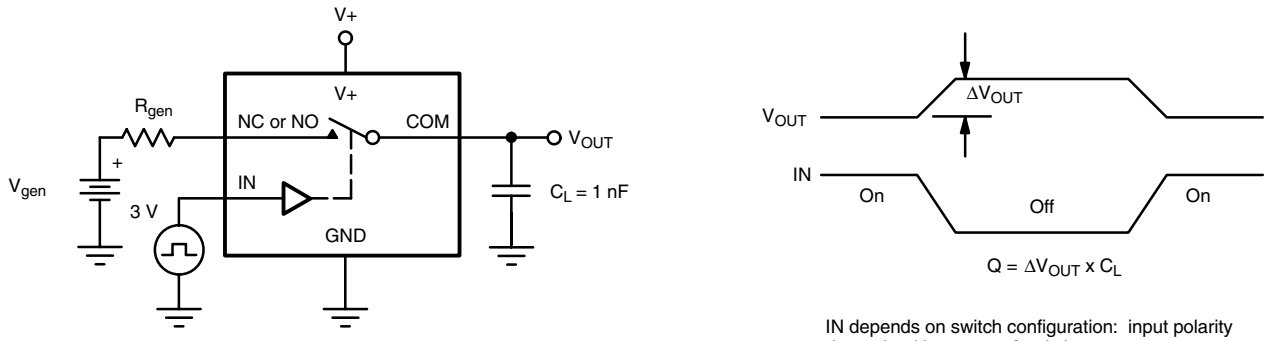


Figure 3. Charge Injection

TEST CIRCUITS

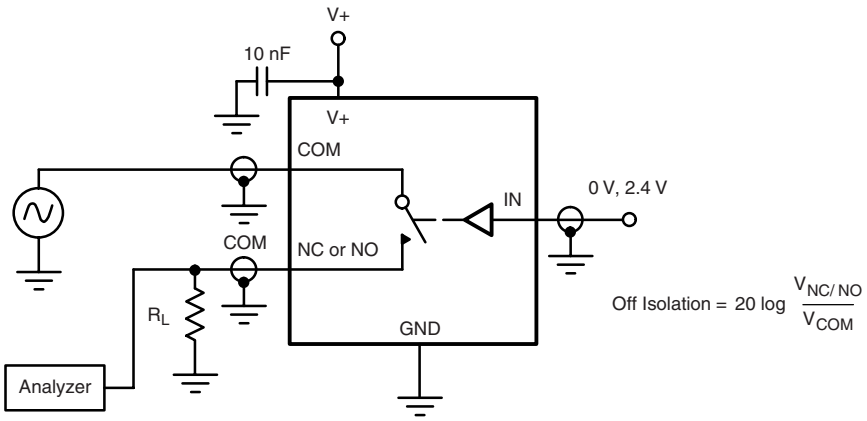


Figure 4. Off-Isolation

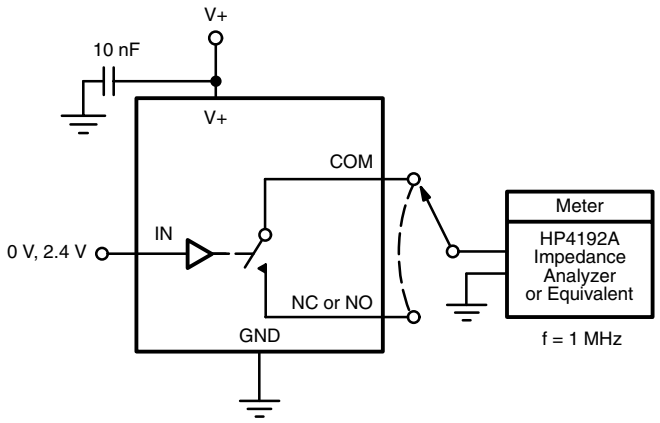


Figure 5. Channel Off/On Capacitance

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